SiC Power Module

SCZ4004DTB Datasheet

Features

- · DOT247 package with the 4th Generation SiC-MOSFET
- \cdot V_{DSS} = 750V
- · Low R_{DS(on)}
- · High-speed switching possible
- · Low switching losses
- · Tvjmax = 175°C
- · Compact design
- · High power density

Construction

The power module is a common source module which implements SiC-MOSFETs.

Application

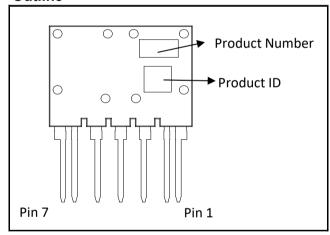
· Inverter, Converter



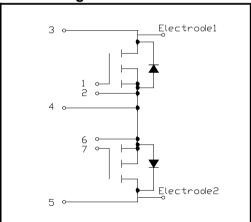


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Outline



Circuit diagram



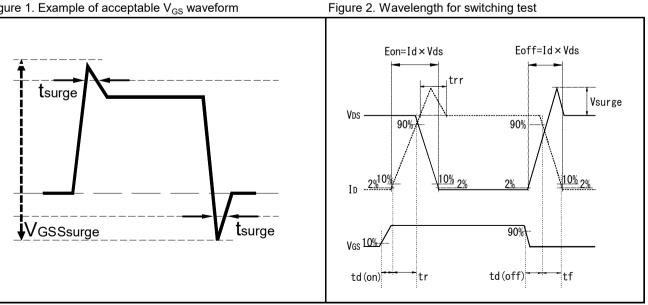
Pin No.	Pin Name	Function
1	G1	MOSFET Gate
2	S1	MOSFET Source
3	P1	Positive Power
4	N	Negative Power
5	P2	Positive Power
6	S2	MOSFET Source
7	G2	MOSFET Gate

Absolute maximum ratings (Tvj = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Rating	Unit	
Drain - source voltage	V_{DSS}	V _{GS} = 0V	750		
Gate - source voltage (DC)	V_{GSS}		-4 to +21] _v	
Gate - source voltage (t _{surge} < 300ns)	$V_{GSSsurge}$		-4 to +23		
Continuous drain surrent (DC)	,	Tc = 25°C, V _{GS} = 18V	251		
Continuous drain current (DC)	I _D	Tc = 100°C, V _{GS} = 18V	177		
Pulsed drain current	I _{D,pulse}	Pulse 1ms, Tc = 25°C, V _{GS} = 18V Note 2), 5)	459		
Puised drain current		Pulse 1ms, Tc = 100°C, V _{GS} = 18V ^{Note 2), 5)}	323	Α	
Continuous source current (DC)	I _S	Tc = 25°C, V _{GS} = 18V	251		
Pulsed source current	I _{S,pulse}	Pulse 1.5μs, Tc = 25°C, V _{GS} = 18V ^{Note 2)}	459		
Body diode surge forward current	I _{S,pulse}	Pulse 1.5µs, Tc = 25°C, V _{GS} = 0V ^{Note 2), 4), 5)}	334		
Total power dissipation Note 3), 5)	Ptot	Tc = 25°C	704	W	
Virtual junction temperature	Tvj		-40 to +175	°C	
Storage temperature	Tstg		-40 to +125		

- Note 1) If the product is used beyond absolute maximum ratings defined in the specifications, as its internal structure may be damaged, please replace the product with a new one.
- Repetition rate should be kept within the range where temperature rise if die should not exceed Tvjmax. Note 2)
- Note 3) Case temperature (Tc) is defined on the cooper surface just under the chips.
- Note 4) Repetitive pulse, PW≦1.5µs, Duty cycle≦5%
- Note 5) Tvj is less than 175°C.

Figure 1. Example of acceptable V_{GS} waveform



Module (Tvj = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	$R_{\text{th(j-c)}}$	1 arm heating ^{Note 3)}	-	0.17	0.22	°C/W

MOSFET electrical characteristics (Tvj = 25°C unless otherwise specified)

Parameter	Symbol	Symbol Conditions -		Values			Unit
Parameter	Syllibol			Min.	Тур.	Max.	Offic
Drain - Source	R	$I_D = 188A, V_{GS} = 18V$	Tvj = 25°C	_	4	5	mΩ
on resistance	$R_{DS(on)}$	1D - 100A, VGS - 10V	Tvj = 150°C	_	8	١	11122
Zero gate voltage drain current	I _{DSS}	V _{DS} = 750V, V _{GS} = 0V		_	-	160	μΑ
Gate - source threshold voltage	$V_{\text{GS(th)}}$	V _{DS} = 10V, I _D = 100mA ^{Note 6)}		2.8	-	4.8	V
Gate - source	1	$V_{GS} = +21V, V_{DS} = 0V$ $V_{GS} = -4V, V_{DS} = 0V$		_	_	0.2	пΔ
leakage current	I _{GSS}			-0.2	_	_	μA
Turn - on delay time	$t_{d(on)}$	$V_{GS(on)} = 18V, V_{GS(off)} = 0V$ $V_{DS} = 400V$ $I_{D} = 188A$ $R_{G(on)} = 10\Omega, R_{G(off)} = 10\Omega$ Inductive load		_	97	ı	ns
Rise time	t _r			_	93	1	
Turn - off delay time	$t_{d(off)}$			_	344	_	
Fall time	t _f			_	34	_	
Turn - on switching loss	E_{on}			_	5.0	_	mJ
Turn - off switching loss	E_{off}			_	4.2	_	IIIJ
Input capacitance	C_{iss}	V _{DS} = 500V, V _{GS} = 0V, 1MHz		_	14.7	_	nF
Total gate charge	Q_g	$V_{GS(on)} = 18V, V_{GS(off)} = 0V$ $V_{DS} = 500V$ $I_{D} = 188A$		_	520	_	
Gate - source charge	Q_gs			_	112	_	nC
Gate - drain charge	Q_{gd}			_	140	ı	
Internal gate resistance	R_{Gint}	Tvj = 25°C		_	0.5	_	Ω

Note 6) Tested after applying $V_{GS} = 21V$ for 100ms.

Body diode electrical characteristics (Tvj = 25°C unless otherwise specified)

Parameter	Symbol	Conditions -		Values			Unit
	Symbol			Min.	Тур.	Max.	Offic
	V_{SD}	V _{GS} = 0V, I _S = 188A	Tvj = 25°C	_	3.3	_	
Souce - drain voltage			Tvj = 150°C	1	3.4	1	
		Vcs =18V. ls = 188A ►	Tvj = 25°C	ı	0.76	ı	ď
			Tvj = 150°C	ı	1.21	ı	

Figure 3. Output characteristic at 25°C (Typ.)

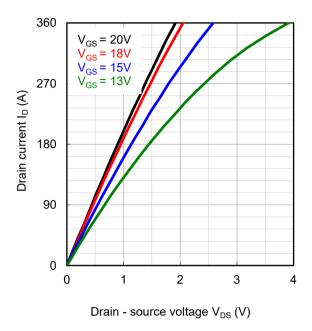


Figure 4. Drain - source voltage characteristic (Typ.)

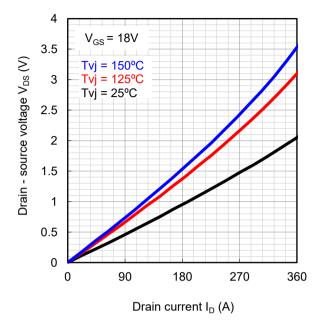


Figure 5. Drain - source voltage characteristic at 25°C (Typ.)

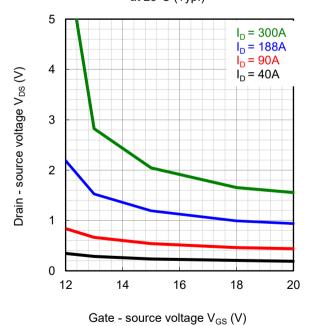
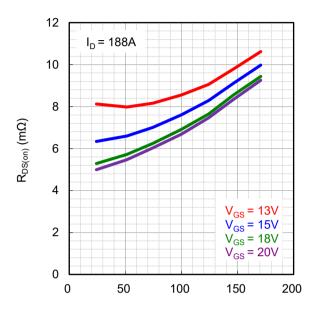


Figure 6. R_{DS(on)} vs. Tvj characteristic (Typ.)



Virtual junction temperature Tvj (°C)

Figure 7. Forward characteristic of diode V_{GS} = 18V (Typ.)

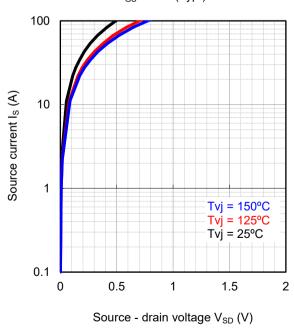
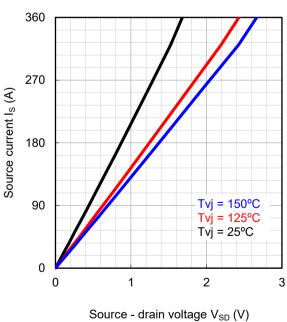
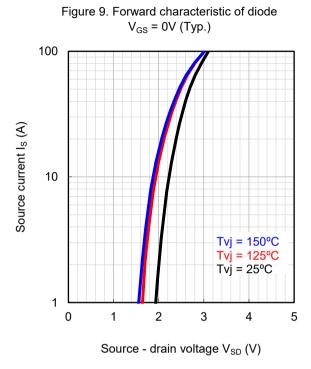


Figure 8. Forward characteristic of diode V_{GS} = 18V (Typ.)





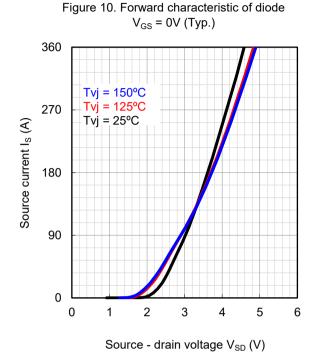
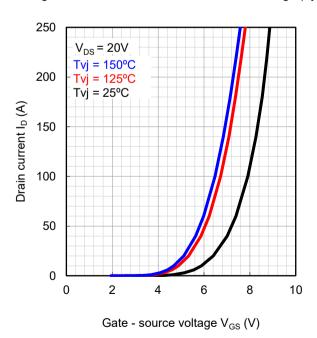


Figure 11. Drain current vs. Gate - source voltage (Typ.) Figure 12. Drain current vs. Gate - source voltage (Typ.)



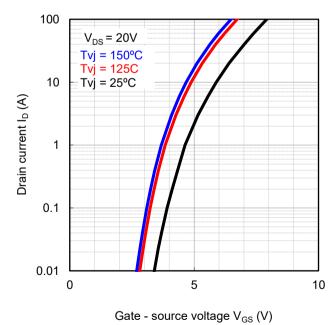


Figure 13. Switching time vs. Drain current at 25°C (Typ.) 1000 $t_{d(off)}$ $t_{d(on)}$ Switching time (ns) 100 10 $V_{DS} = 400V$ $R_{G(on)} = 8.2\Omega$ $R_{G(off)} = 10\Omega$ INDUCTIVE LOAD $V_{GS(on)} = 18V$ $V_{GS(off)} = 0V$ 0 100 200 300 400 Drain current I_D (A)

at 150°C (Typ.)

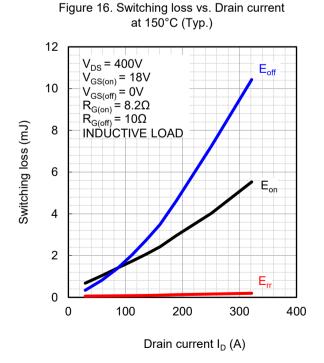
1000 $t_{d(off)}$ 100 $t_{d(off)}$ t_{r} t_{r}

Figure 14. Switching time vs. Drain current

 $\begin{array}{c} 12 \\ V_{DS} = 400V \\ V_{GS(on)} = 18V \\ V_{GS(off)} = 0V \\ R_{G(on)} = 8.2\Omega \\ R_{G(off)} = 10\Omega \\ \hline INDUCTIVE LOAD \\ \end{array}$

Figure 15. Switching loss vs. Drain current

at 25°C (Typ.)



100

200

Drain current I_D (A)

2

0

0

En

400

300

Figure 17. Recovery characteristic vs. Drain current at 25°C (Typ.)

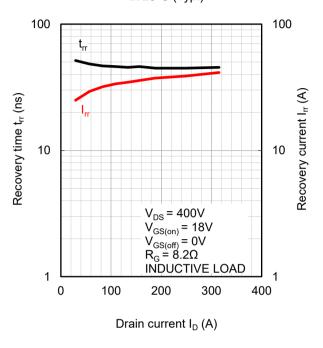


Figure 18. Recovery characteristic vs. Drain current at 150°C (Typ.)

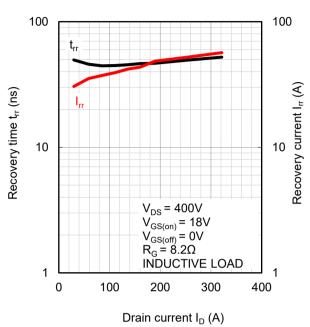


Figure 19. Switching time vs. Gate resistance at 25°C (Typ.)

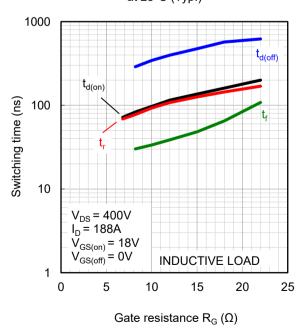


Figure 20. Switching time vs. Gate resistance at 150°C (Typ.)

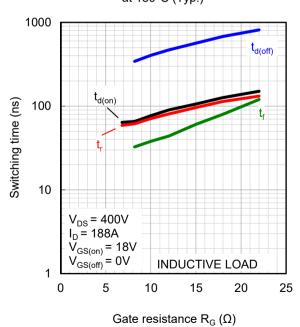


Figure 21. Switching loss vs. Gate resistance at 25°C (Typ.)

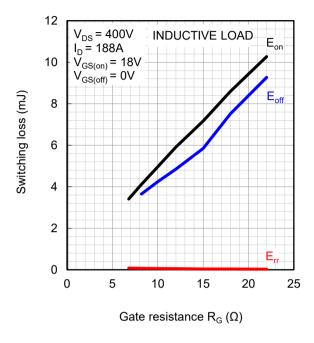


Figure 22. Switching loss vs. Gate resistance at 150°C (Typ.)

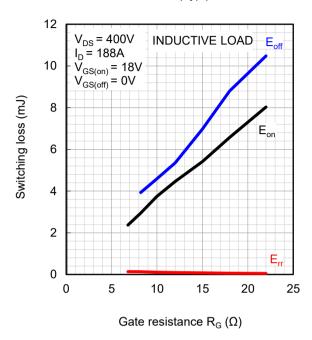


Figure 23. Capacitance vs. Drain - source voltage at 25°C (Typ.)

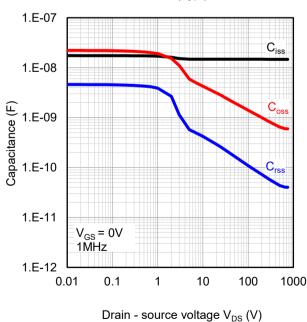


Figure 24. Gate charge characteristic at 25°C (Typ.)

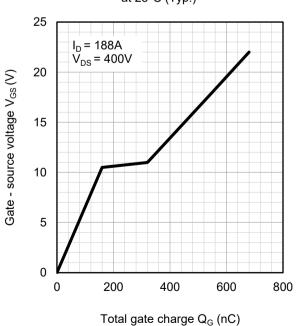
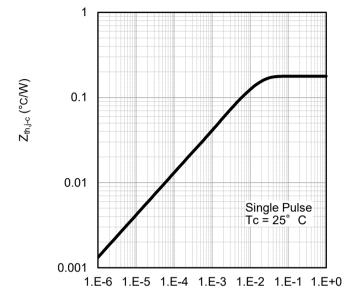
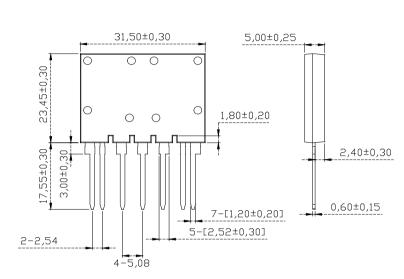


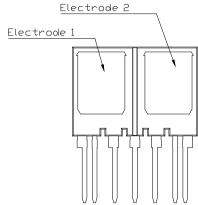
Figure 25. Transient thermal impedance (Typ.)



Package outlines



Unit: mm



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